

Table 1. Main characteristics

Symbol	Value	Unit
$I_T(\text{rms})$	4	A
$V_{\text{DRM}}, V_{\text{RRM}}$	600 to 800	V
I_{GT}	5 to 35	mA

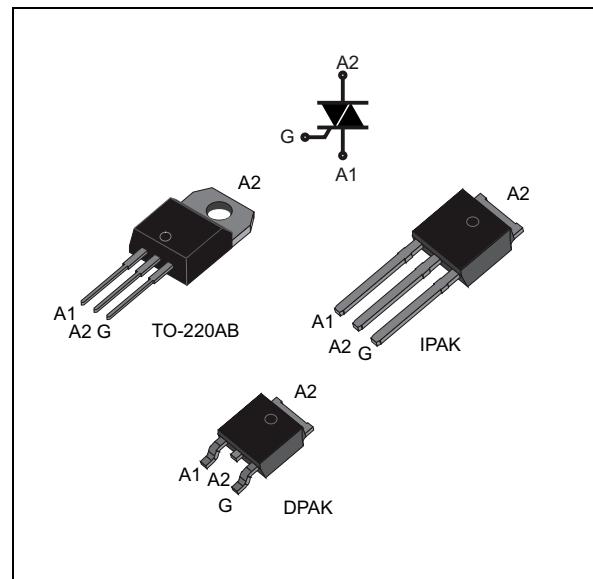
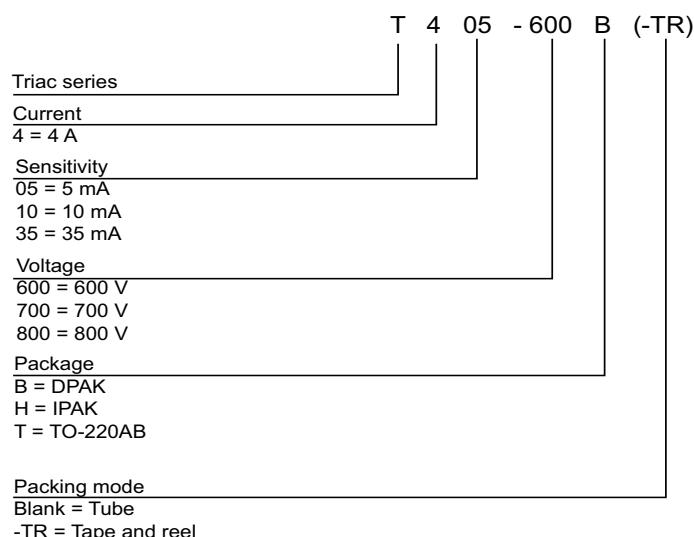


Figure 1. Order information scheme



1.Characteristics

Table2. Absolute maximum ratings ($T_j = 25^\circ\text{C}$ unless otherwise stated)

Symbol	Parameter			Value	Unit
$I_{T(\text{rms})}$	On-state rms current (full sine wave)	IPAK, DPAK, TO-220AB	$T_c = 110^\circ\text{C}$	4	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	$F = 50 \text{ Hz}$	$t = 20 \text{ ms}$	30	A
		$F = 60 \text{ Hz}$	$t = 16.7 \text{ ms}$	31	
I^2t	I^2t value for fusing		$t_p = 10 \text{ ms}$	5.1	A^2s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100 \text{ ns}$	$F = 120 \text{ Hz}$	$T_j = 125^\circ\text{C}$	50	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$t_p = 20 \mu\text{s}$	$T_j = 125^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ\text{C}$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to +150 - 40 to +125	$^\circ\text{C}$

Table3. Electrical characteristics ($T_j = 25^\circ\text{C}$, unless otherwise stated)

Symbol	Test conditions	Quadrant		Value			Unit
				T405	T410	T435	
$I_{GT}^{(1)}$	$V_D = 12 \text{ V}$, $R_L = 30 \Omega$	I - II - III	Max.	5	10	35	mA
V_{GT}	$V_D = 12 \text{ V}$, $R_L = 30 \Omega$	I - II - III	Max.	1.3			V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$, $T_j = 125^\circ\text{C}$	I - II - III	Min.	0.2			V
$I_H^{(2)}$	$I_T = 100 \text{ mA}$		Max.	10	15	35	mA
I_L	$I_G = 1.2 I_{GT}$	I - III	Max.	10	25	50	mA
		II	Max.	15	30	60	
$dV/dt^{(2)}$	$V_D = 67\% V_{DRM}$, gate open	$T_j = 125^\circ\text{C}$	Min.	20	40	400	$\text{V}/\mu\text{s}$
$(dI/dt)c^{(2)}$	($dV/dt)c = 0.1 \text{ V}/\mu\text{s}$	$T_j = 125^\circ\text{C}$	Min.	1.8	2.7		A/ms
	$(dV/dt)c = 10 \text{ V}/\mu\text{s}$			0.9	2.0		
	(without snubber)					2.5	

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. For both polarities of A2 referenced to A1

Table4. Static characteristics

Symbol	Test conditions			Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 5.5 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 25^\circ\text{C}$	Max.	1.56	V
$V_{t0}^{(1)}$	Threshold voltage	$T_j = 125^\circ\text{C}$	Max.	0.89	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 125^\circ\text{C}$	Max.	120	$\text{m}\Omega$
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	Max.	5	μA
		$T_j = 125^\circ\text{C}$		1	mA

1. For both polarities of A2 referenced to A1

Table5. Thermal resistance

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case (AC)		IPAK, DPAK, TO-220AB	2.6	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient	$S^{(1)} = 0.5 \text{ cm}^2$	DPAK	70	$^\circ\text{C/W}$
	Junction to ambient		TO-220AB	60	$^\circ\text{C/W}$
			IPAK	100	$^\circ\text{C/W}$

1. S = Copper surface under tab.

Figure2. Maximum power dissipation versus RMS on-state current (full cycle)

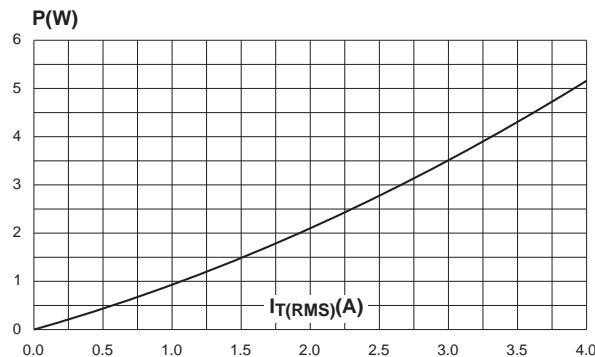


Figure3. RMS on-state current versus case temperature (full cycle)

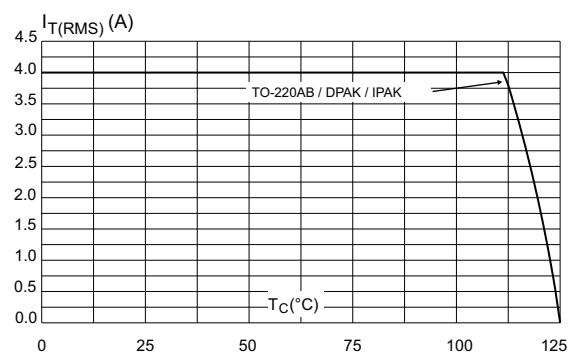


Figure4. RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35μm) (full cycle)

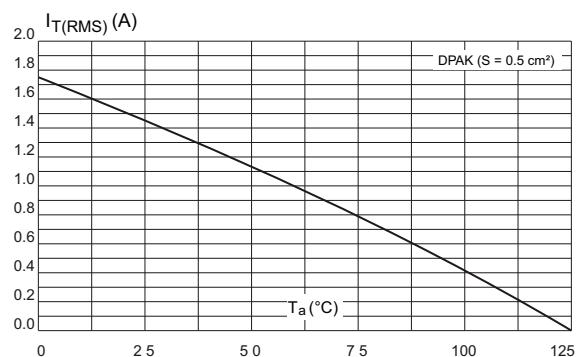


Figure5. Relative variation of thermal impedance versus pulse duration

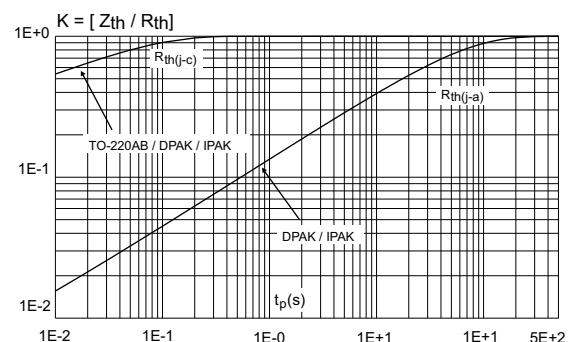


Figure6. On-state characteristics (maximum values)

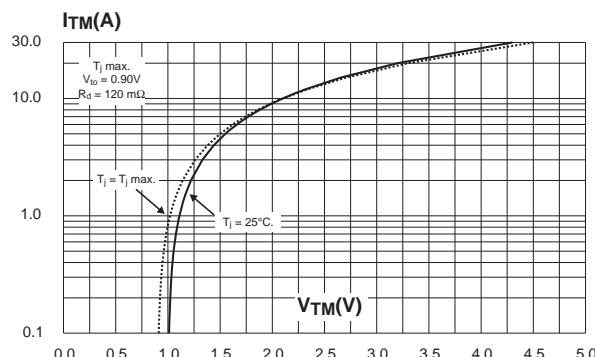


Figure7. Surge peak on-state current versus number of cycles

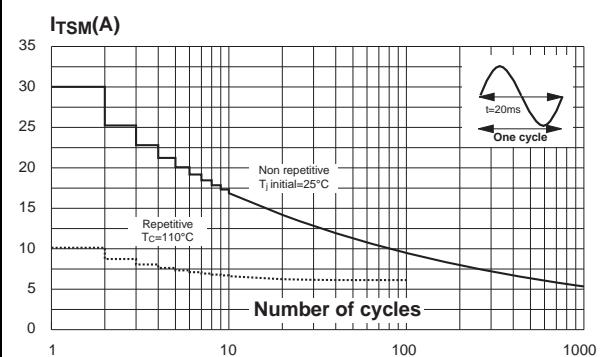


Figure8. Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms

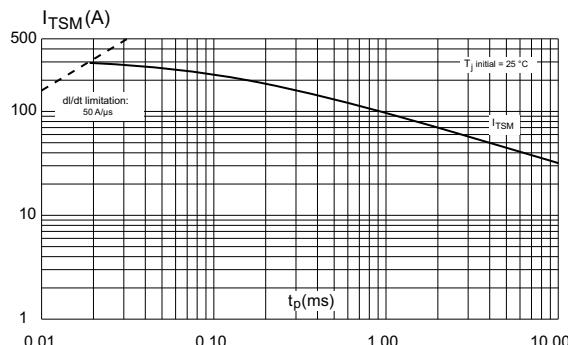


Figure9. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

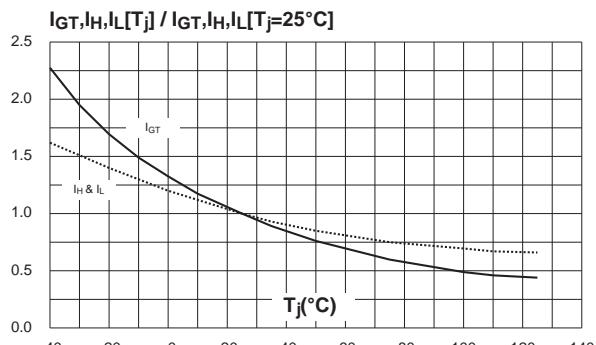


Figure10. Relative variation of critical rate of decrease of main current versus $(dV/dt)c$ (typical values)

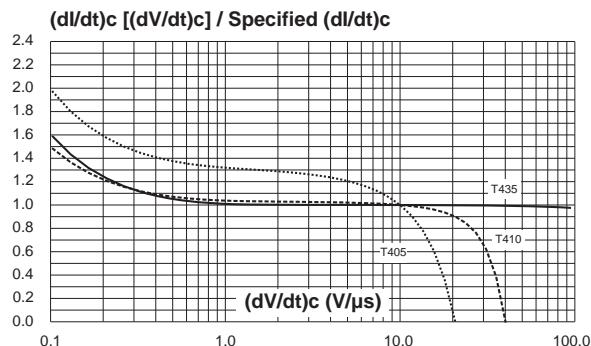


Figure 11. Relative variation of critical rate of decrease of main current versus junction temperature

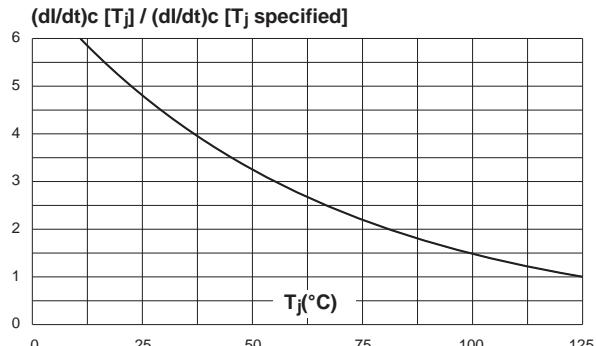


Figure 12. DPAK thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 μm)

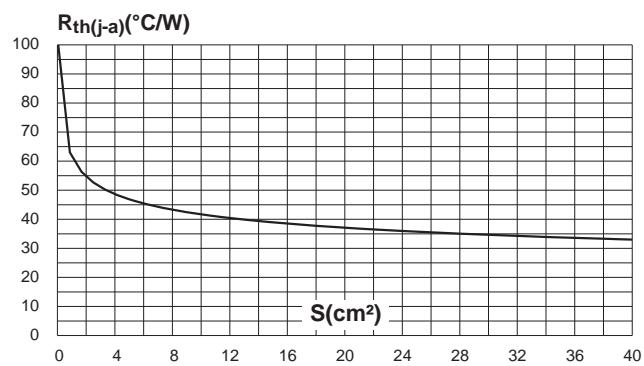


Figure 13. DPAK package outline

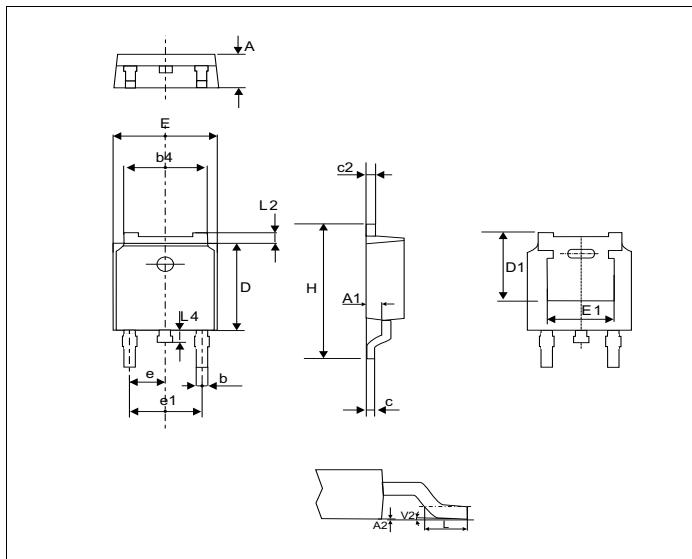


Table6. DPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.18		2.40	0.086		0.0944
A1	0.9		1.10	0.035		0.0433
A2	0.03		0.23	0.0011		0.0090
b	0.64		0.90	0.0251		0.0354
b4	4.95		5.46	0.1948		0.2149
c	0.46		0.61	0.0181		0.0240
c2	0.46		0.60	0.0181		0.0236
D	5.97		6.22	0.2350		0.2448
D1	4.95			0.1948		
E	6.35		6.73	0.2500		0.2649
E1	4.32			0.1700		
e		2.286			0.09	
e1		4.572			0.18	
H	9.35		10.40	0.3681		0.4094
L	1.0		1.78	0.039		0.0700
L2			1.27			0.0500
L4	0.6		1.02	0.023		0.0401
V2	-8°		+8°	-8°		+8°

Figure 14. IPAK package outline

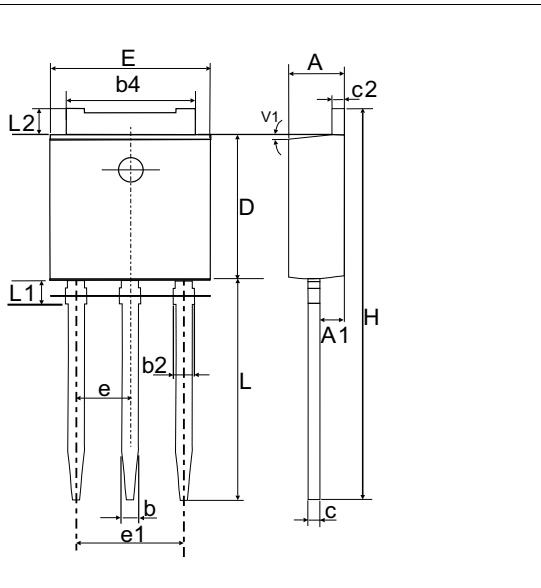


Table7. IPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.0866		0.0945
A1	0.90		1.10	0.0354		0.0433
b	0.64		0.90	0.0252		0.0354
b2			0.95			0.0374
b4	5.20		5.43	0.2047		0.2138
c	0.45		0.60	0.0177		0.0236
c2	0.46		0.60	0.0181		0.0236
D	6		6.20	0.2362		0.2441
E	6.40		6.65	0.2520		0.2618
e		2.28			0.0898	
e1	4.40		4.60	0.1732		0.1811
H		16.10			0.6339	
L	9		9.60	0.3543		0.3780
L1	0.8		1.20	0.0315		0.0472
L2		0.80	1.25		0.0315	0.0492
V1		10°			10°	

1. Inch dimensions are only for reference

Figure 15. Footprint (dimensions in mm)

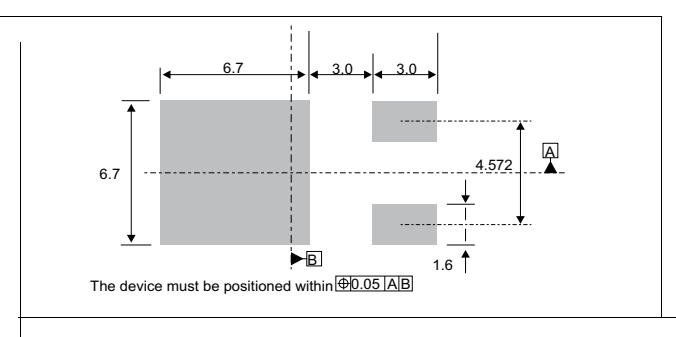


Figure 16. TO-220AB (insulated and non-insulated) package outline

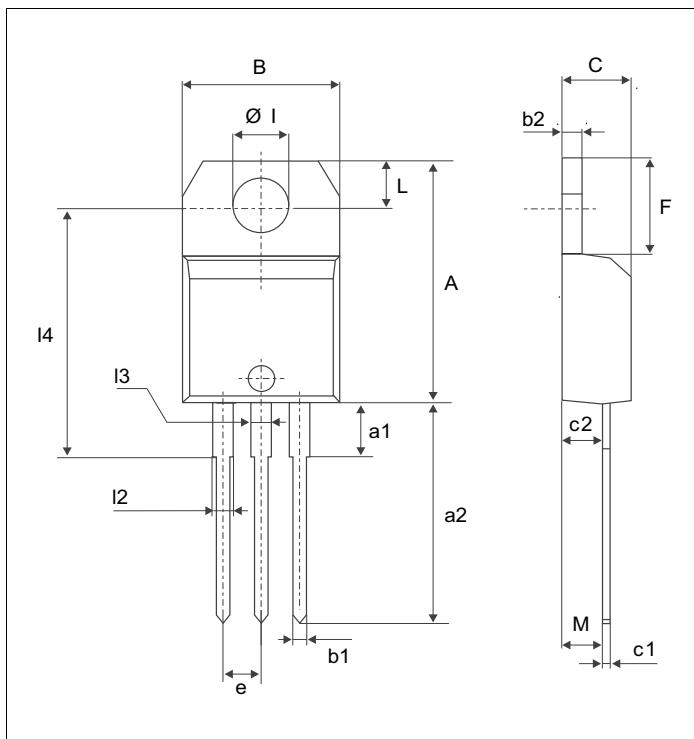


Table 8. TO-220AB (insulated and non-insulated) package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6259
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5511
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0519
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0192		0.0275
c2	2.40		2.72	0.0944		0.1070
e	2.40		2.70	0.0944		0.1062
F	6.20		6.60	0.2440		0.2598
Øl	3.73		3.88	0.1468		0.1527
I4	15.80	16.40	16.80	0.6220	0.6456	0.6614
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0448		0.0669
l3	1.14		1.70	0.0448		0.0669
M		2.60			0.1023	

1. Inch dimensions are only for reference

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